# NSN 5961-01-054-6192

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#### Inclosure Material:

Metal

#### **Overall Length:**

Between 0.320 inches and 0.468 inches

# Mounting Facility Quantity:

1

#### Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-59

#### **Mounting Method:**

Threaded stud

Features Provided:

Hermetically sealed case

#### **Overall Width Across Flats:**

Between 0.424 inches and 0.437 inches

Thread Size:

0.190 inches

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 6.0

breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

Between 2.00 amperes source cutoff current and 5.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

50.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Thread Series Designator:**

Unf

# **Terminal Type And Quantity:**

3 tab, solder lug

# **Specification Data:**

80131-release5569 professional/industrial association specification

# Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

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